NSN 5962-00-524-1983

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View Online at https://aerobasegroup.com/nsn/5962-00-524-1983
Body Length:
Between 0.240 inches and 0.275 inches
Body Width:
Between 0.240 inches and 0.260 inches
Body Height:
Between 0.030 inches and 0.070 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/enable and w/decoded output and resettable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
7 input
Case Outline Source And Designator:
T0-86 joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds propagation delay time, low to high level output and 20.00 nanoseconds propagation delay time, high to low lev
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
13499-351-7527 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

14 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Vec - demil/mli

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